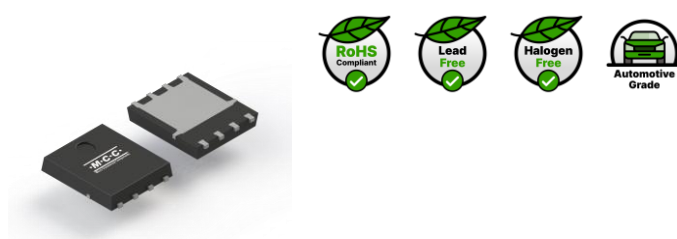


150V N-Channel Automotive Grade MOSFET

Product Summary

Parameter	Rating
V _{DS}	150V
I _D	70 A
R _{DS(on)} Max	17 mΩ



DFN5060

Features

- AEC-Q101 qualified
- Split Gate Trench technology
- Excellent gate charge x R_{DS(on)} product (FOM)
- Low Q_g for fast response
- Excellent package for heat dissipation

Applications

- Motors driver
- DC-DC converter
- Solar Inverter

Mechanical Data

- Package: DFN5060
- Moisture Sensitivity: Level N, per J-STD-020
- Halogen Free. "Green" Device (Note1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)
- Weight: 0.0878g (approximate)

Body Marking and Pin Layout

Marking Code	Internal Structure
<p>4 codes in total YY = year code WW = week code</p>	

Ordering Information

Product Name	Packing info
MCAC70N15YHE3-TP	5,000pcs/reel

For packaging details, visit our website at <https://www.mccsemi.com/Package/List>

150V N-Channel Automotive Grade MOSFET

 Maximum Ratings ($T_J=25^\circ\text{C}$ unless otherwise specified)

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	150	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuons Drain Curent	$T_C=25^\circ\text{C}, V_{GS}=10\text{V}$	I_D	70	A
	$T_C=100^\circ\text{C}, V_{GS}=10\text{V}$		49	
	$T_A=25^\circ\text{C}, V_{GS}=10\text{V}$		9	
	$T_A=100^\circ\text{C}, V_{GS}=10\text{V}$		6	
Pulsed Drain Current ^(Note2)		I_{DM}	280	A
Total Power Dissipation	$T_C=25^\circ\text{C}, V_{GS}=10\text{V}$	P_D	150	W
	$T_C=100^\circ\text{C}, V_{GS}=10\text{V}$		75	
	$T_A=25^\circ\text{C}, V_{GS}=10\text{V}$		3	
	$T_A=100^\circ\text{C}, V_{GS}=10\text{V}$		1.5	
Single Pulsed Avalanche Energy	$T_J=25^\circ\text{C}, V_{DD}=80\text{V}, V_{GS}=10\text{V}, R_G=25\Omega, L=0.5\text{mH}$	E_{AS}	81	mJ
Avalanche Current		I_{AS}	25.7	A
Operating Junction Temperature Range		T_J	-55 to +175	$^\circ\text{C}$
Storage Temperature Range		T_{STG}	-55 to +175	$^\circ\text{C}$

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and 1000ppm antimony compounds.
2. Repetitive rating; pulse width limited by max. junction temperature

Thermal Characteristics

Parameter		Symbol	Rating	Unit
Thermal Resistance from Junction to Ambient ^(Note 3)		$R_{\theta JA}$	50	$^\circ\text{C/W}$
Thermal Resistance from Junction to Case		$R_{\theta JC}$	1.0	$^\circ\text{C/W}$

Note:

3. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$. The maximum allowed junction temperature of 150 $^\circ\text{C}$. The value in any given application depends on the user's specific board design

150V N-Channel Automotive Grade MOSFET

 Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	150			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 120V, V _{GS} =0V			1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	2.0	2.9	4.0	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A		13	17	mΩ
		V _{GS} =6V, I _D =10A		17	22	
Gate Resistance	R _g	F=1 MHz, Open drain		0.9		Ω
Diode Characteristics						
Continuous Body Diode Current	I _s				70	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _s =20A			1.2	V
Reverse Recovery Time	t _{rr}	I _F =20A, dI _{SD} /dt=100A/μs			93	ns
Reverse Recovery Charge	Q _{rr}			214		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =75V, V _{GS} =0V, f=1MHz		2527		pF
Output Capacitance	C _{oss}			207		
Reverse Transfer Capacitance	C _{rss}			7		
Total Gate Charge	Q _g	V _{DS} =75V, V _{GS} =10V, I _D =20A		40		nC
Gate-Source Charge	Q _{gs}			10		
Gate-Drain Charge	Q _{gd}			11		
Turn-On Delay Time	t _{d(on)}	V _{DD} =75V, V _{GS} =10V, R _{GEN} =4.5Ω, I _{DS} =20A		15		ns
Turn-On Rise Time	t _r			14		
Turn-Off Delay Time	t _{d(off)}			29		
Turn-Off Fall Time	t _f			13		

150V N-Channel Automotive Grade MOSFET

Curve Characteristics

Fig. 1 - Typical Output Characteristics

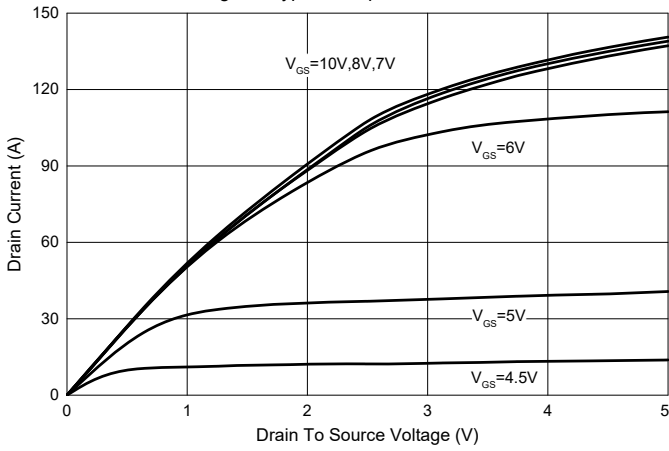


Fig. 2 - Transfer Characteristics

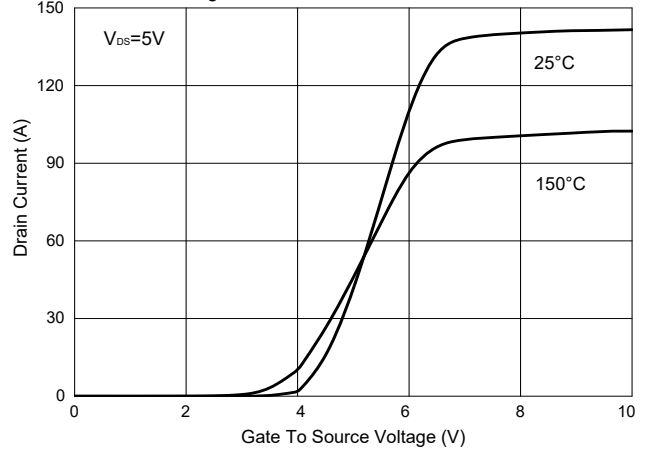


Fig. 3 - $R_{DS(ON)}$ — V_{GS}

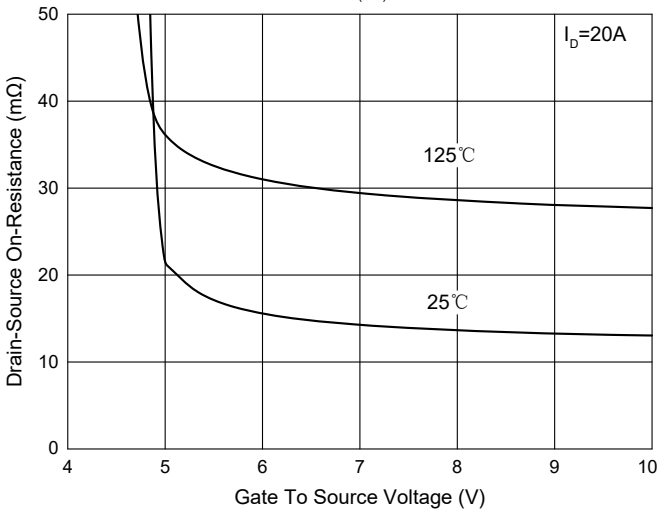


Fig. 4 - $R_{DS(ON)}$ — I_D

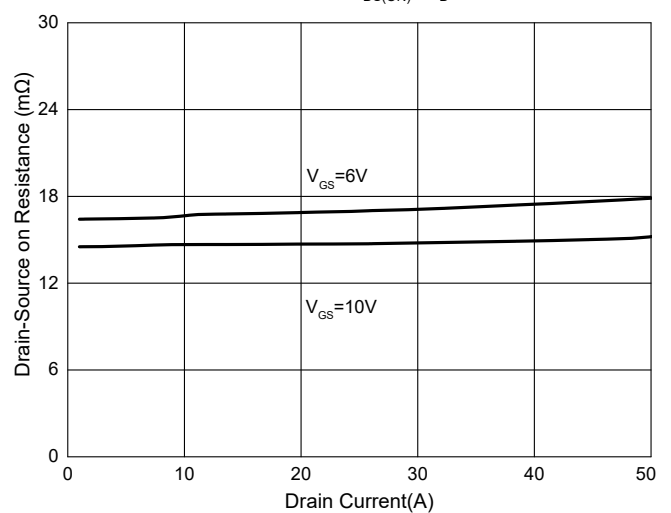


Fig. 5 - Capacitance Characteristics

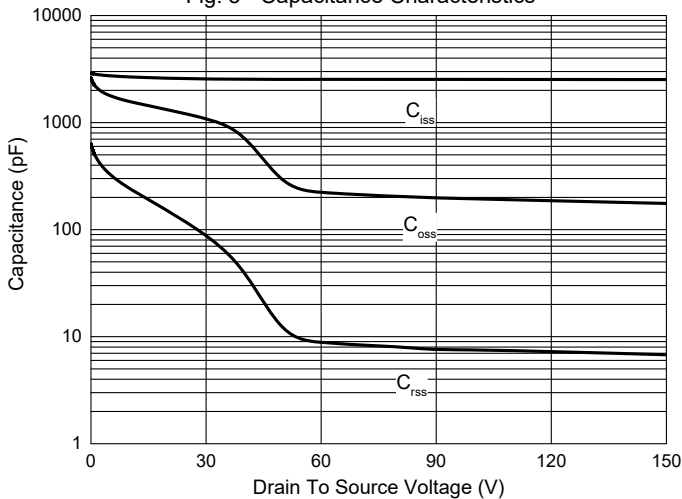
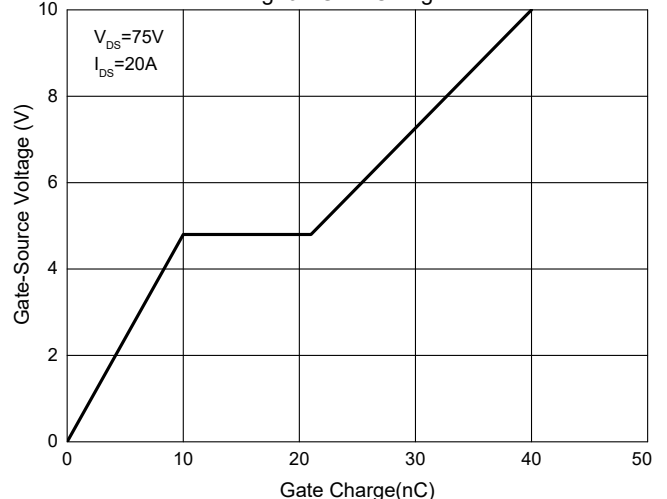


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Normalized Threshold Voltage

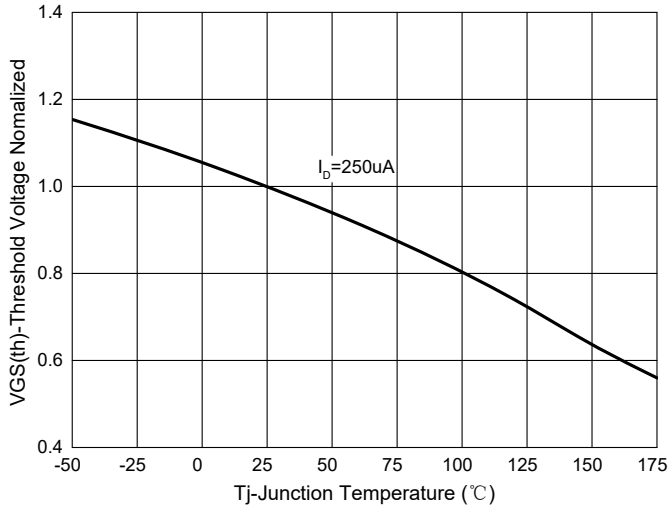


Fig.8-Normalized On Resistance Characteristics

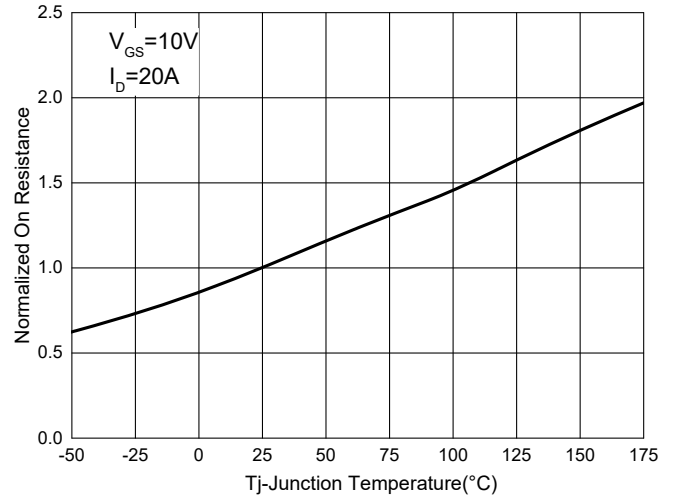


Fig. 9 - I_s—V_{SD}

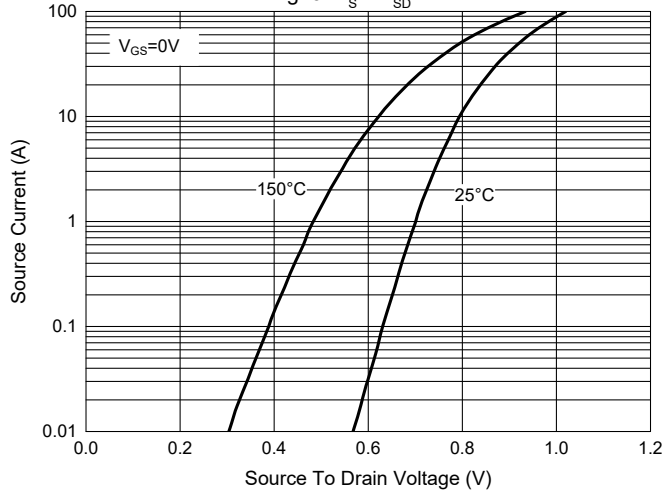


Fig. 10 - Drain Current

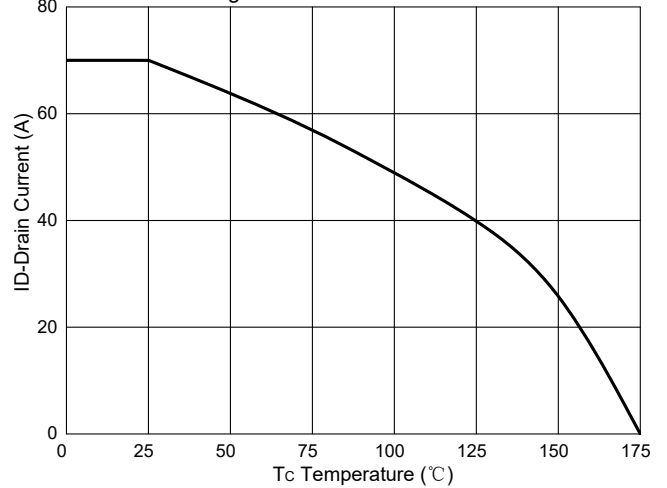
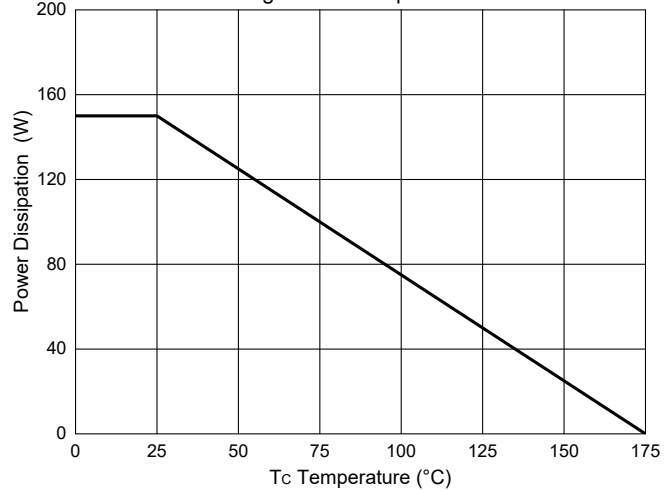


Fig.11-PD Dissipation



Curve Characteristics

Fig. 12 - Safe Operation Area

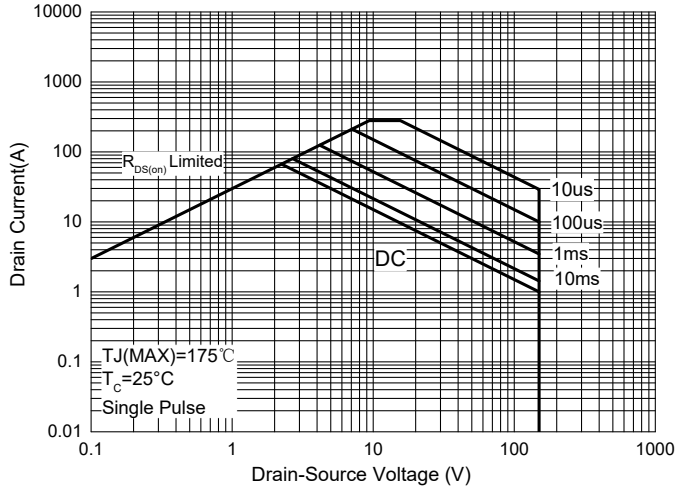
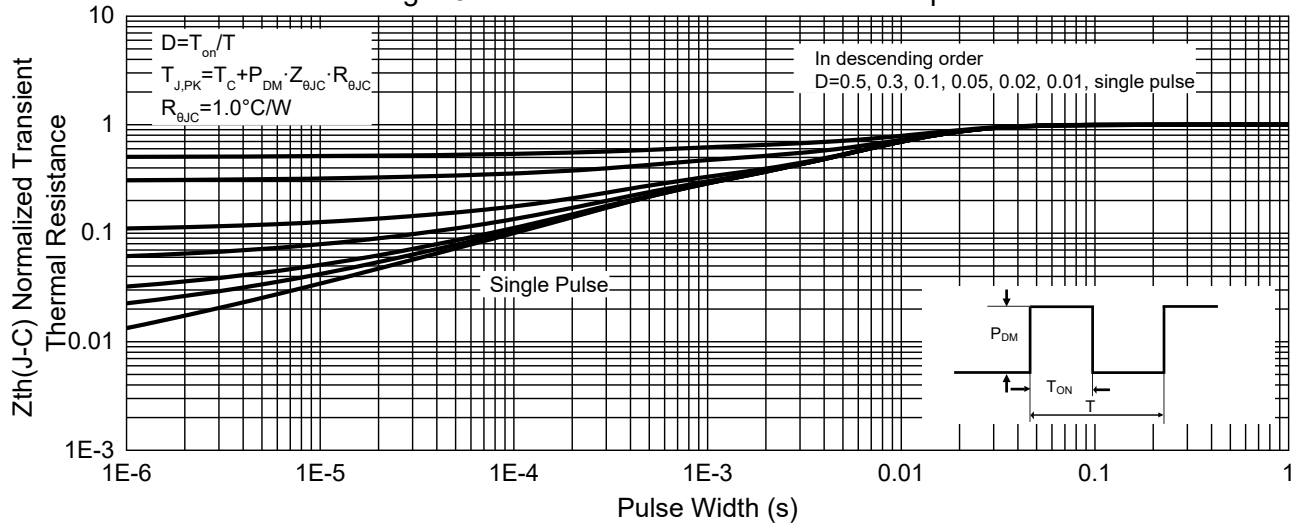
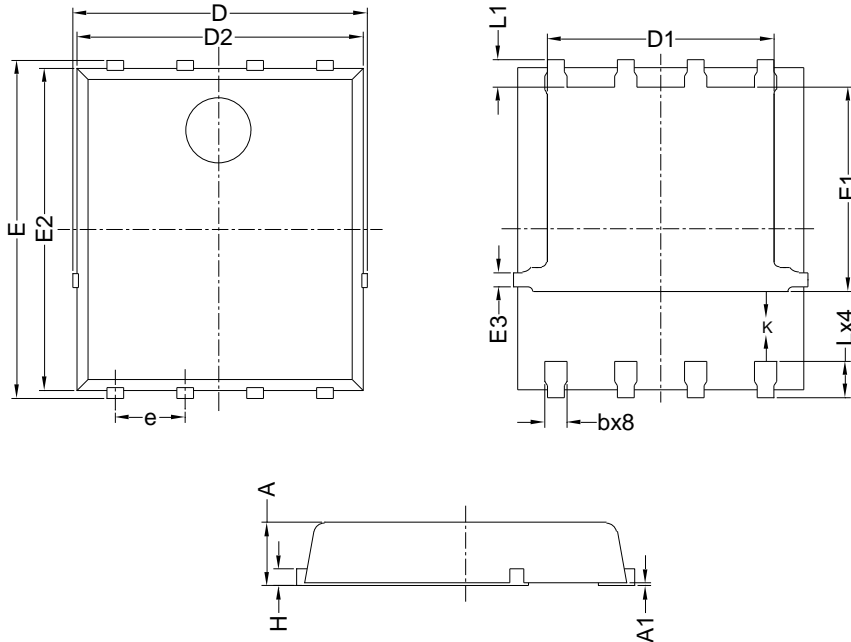


Fig. 13 - Normalized Transient Thermal Impedance

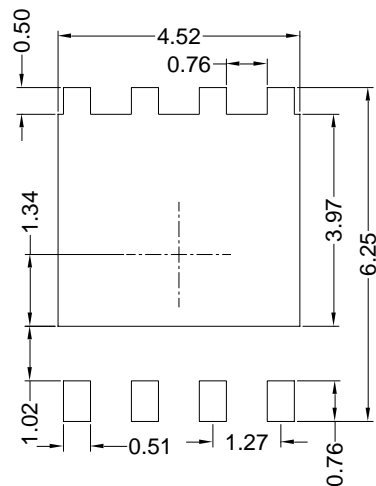


Package Outline



DIM	INCH		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.039	0.047	1.00	1.20	
A1		0.003		0.1€	
b	0.012	0.020	0.30	0.50	
D	0.193	0.222	4.90	5.64	
D1	0.148	0.167	3.75	4.25	
D2	0.189	0.213	4.80	5.40	
E	0.232	0.250	5.90	6.35	
E1	0.126	0.154	3.20	3.92	
E2	0.222	0.239	5.65	6.06	
E3	0.010		0.254		REF
e	0.046	0.054	1.17	1.37	
H	0.010		0.254		BSC
K	0.045	0.059	1.15	1.50	
L	0.012	0.028	0.30	0.71	
L1	0.016	0.028	0.40	0.71	

Suggested Pad Layout (Unit:mm)



Notes:

1. The suggested land pattern dimensions have been provided for reference only.
2. For further information, please reference document IPC-7351A.

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